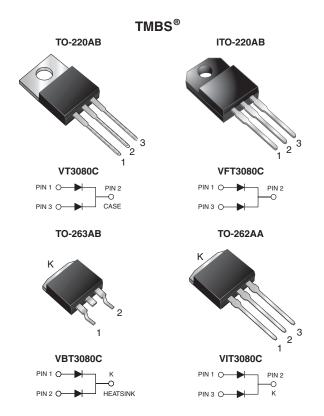
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Vishay General Semiconductor

Dual Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.46 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS							
I _{F(AV)}	2 x 15 A						
V_{RRM}	80 V						
I _{FSM}	150 A						
V_F at $I_F = 15$ A	0.65 V						
T _J max.	150 °C						
Package	TO-220AB, ITO-220AB, TO-263AB, TO-262AA						
Diode variation	Common cathode						

FEATURES





- · Low forward voltage drop, low power losses
- · High efficiency operation

e3

RoHS

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)									
PARAMETER		SYMBOL	VT3080C	VFT3080C	VBT3080C	VIT3080C	UNIT		
Maximum repetitive peak reverse voltage			80				V		
Maximum average forward rectified average (fig. 1)	per device		30			A			
Maximum average forward rectified current (fig. 1)	per diode	I _{F(AV)}	15						
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	150				Α		
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH per diode		E _{AS}	160			mJ			
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode		I _{RRM}	1.0			Α			
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500				V		
Operating junction and storage temperature range		T _J , T _{STG}	-55 to +150			°C			

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	- V _F ⁽¹⁾	0.52	-	V	
	I _F = 7.5 A			0.58	-		
	I _F = 15 A			0.75	0.82		
	I _F = 5 A	T _A = 125 °C		0.46	-		
	I _F = 7.5 A			0.52	-		
	I _F = 15 A			0.65	0.70		
Reverse current per diode	V _R = 80 V	T _A = 25 °C T _A = 125 °C	I _R ⁽²⁾	30	700	μΑ	
	v _R = 60 v			20	35	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	VT3080C	3080C VFT3080C VBT3080C VIT3080C UNI				
Typical thermal resistance	per diode	$R_{ hetaJC}$	2.5	6.0	2.5	2.5	°C/W	
	per device		2.0	5.0	2.0	2.0		

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	VT3080C-E3/4W	1.89	4W	50/tube	Tube			
ITO-220AB	VFT3080C-E3/4W	1.76	4W	50/tube	Tube			
TO-263AB	VBT3080C-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VBT3080C-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VIT3080C-E3/4W	1.46	4W	50/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

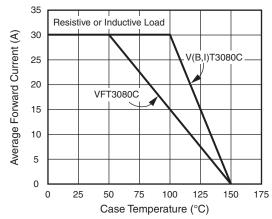


Fig. 1 - Maximum Forward Current Derating Curve

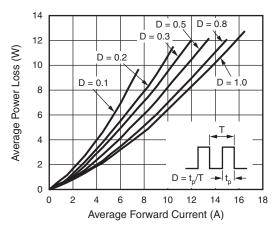


Fig. 2 - Forward Power Loss Characteristics Per Diode

10 000

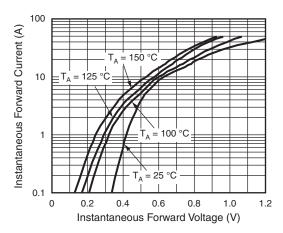


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

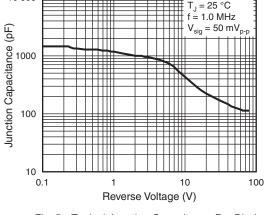


Fig. 5 - Typical Junction Capacitance Per Diode

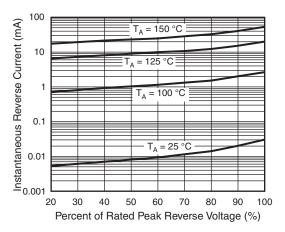


Fig. 4 - Typical Reverse Characteristics Per Diode

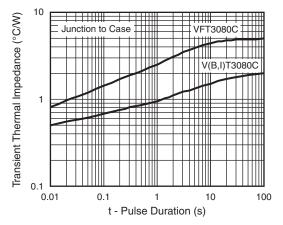


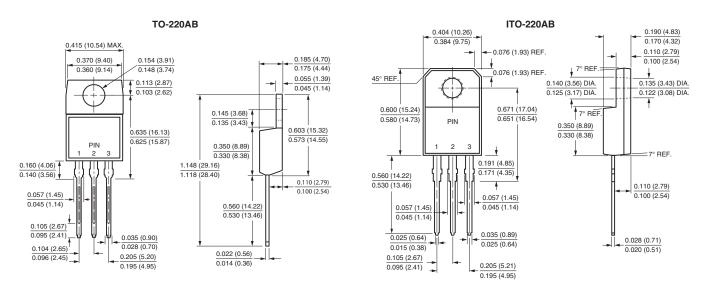
Fig. 6 - Typical Transient Thermal Impedance Per Device



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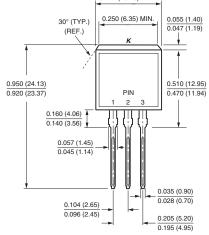
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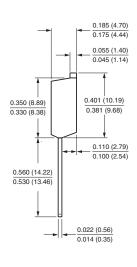
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



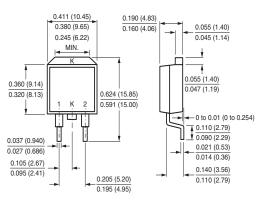
TO-262AA

0.411 (10.45) MAX

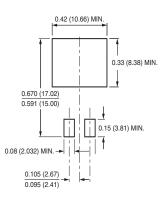




TO-263AB



Mounting Pad Layout





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Revision: 02-Oct-12 Document Number: 91000